

AMENDMENTS TO THE CLAIMS

This listing of claims will replace all prior versions and listings of claims in the application:

LISTING OF CLAIMS:

Claims 1-17 (canceled).

18. (currently amended): A high-strength, low-temperature-sintered ceramic composition having a structure comprising ~~hexagonal crystal phases of~~ SrAl₂Si₂O₈₈ and an Al₂O₃ crystal ~~titanium oxide and silicon oxide, respectively, at least part of said crystal phase of SrAl₂Si₂O₈ determined by an X-ray diffraction measurement being composed of hexagonal SrAl₂Si₂O₈~~, said ceramic composition having a bending strength of 300 MPa or more.

19. (currently amended): ~~A~~The high-strength, low-temperature-sintered ceramic composition according to claim 18, comprising hexagonal SrAl₂Si₂O₈ in an Al₂O₃-SiO₂-SrO-based matrix, which contains an Al₂O₃ crystal ~~grains, a TiO₂ crystal and a SiO₂ crystal~~ ~~and has a bending strength of 300 MPa or more.~~

20. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim 19, wherein a part of said matrix is an amorphous phase, ~~in which hexagonal SrAl₂Si₂O₈ is precipitated.~~

21. (canceled).

22. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim 19, wherein said matrix ~~contains~~further comprises monoclinic $\text{SrAl}_2\text{Si}_2\text{O}_8$.

23. (currently amended): ~~A~~The high-strength, low-temperature-sintered ceramic composition ~~having a structure comprising a $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal and an Al_2O_3 crystal~~according to claim 18, wherein said $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal being composed of hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ alone or hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ and monoclinic $\text{SrAl}_2\text{Si}_2\text{O}_8$, a peak intensity ratio represented by $I_{101} / (I_{101} + I_{002}) \times 100$ being 5% or more in an X-ray diffraction measurement by a Cu-K α line, wherein I_{101} represents a peak intensity of a (101) plane of the hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$, and I_{002} represents a peak intensity of a (002) plane of the monoclinic $\text{SrAl}_2\text{Si}_2\text{O}_8$, ~~and said ceramic composition having a bending strength of 300 MPa or more.~~

24. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim ~~23~~18, wherein said peak intensity ratio is 50% or more.

25. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim ~~23~~18, ~~which has a structure comprising a matrix substantially composed of the $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal, which contains Al_2O_3 crystal grains, said $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal being composed of hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ alone or hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ and monoclinic $\text{SrAl}_2\text{Si}_2\text{O}_8$, and wherein a percentage ratio of said hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ in said $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal being 60% or more, and said ceramic composition having a bending strength of 400 MPa or more.~~

26. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim 18, wherein said Al_2O_3 crystal ~~grams leave is in the form of~~ grains and said grains have an average diameter of 1 μm or less.

27. (currently amended): The high-strength, low-temperature-sintered ceramic composition according to claim 18, wherein it comprises ~~(a) 100% by mass of main components comprising (a) 10-60% by mass of Al (as Al_2O_3), 25-60% by mass of Si (as SiO_2) and 7.5-50% by mass of Sr (as SrO), (b) auxiliary components comprising at least one selected from the group consisting of 0.1-10% by mass of Bi (as Bi_2O_3), 0.1-5% by mass of Na (as Na_2O), 0.1-5% by mass, of K (as K_2O) and 0.1-5% by mass of Co (as CoO), and at least one selected from the group consisting of 0.01-5% by mass of Cu (as CuO), 0.01-5% by mass of Mn (as MnO_2), 0.01-5% by mass of Ag and 0.01-2% by mass of Zr (as ZrO_2); and (c) inevitable impurities.~~

28. (currently amended): ~~The A~~ high-strength, low-temperature-sintered ceramic composition according to claim 18 having a structure comprising $\text{SrAl}_2\text{Si}_2\text{O}_8$ and Al_2O_3 , said ceramic composition having a bending strength of 300 MPa or more, wherein it comprises (a) 100% by mass of main components comprising 10-60% by mass of Al (as Al_2O_3), 25-60% by mass of Si (as SiO_2), 7.5-50% by mass of Sr (as SrO) ~~and 20% or less by mass of Ti (as TiO_2),~~ (b) auxiliary components comprising at least one selected from the group consisting of 0.1-10% by mass of Bi (as Bi_2O_3), 0.1-5% by mass of Na (as Na_2O), 0.1-5% by mass of K (as K_2O) and 0.1-5% by mass of Co (as CoO), and at least one selected from the group consisting of 0.01-5% by mass of Cu (as CuO), 0.01-5% by mass of Mn (as MnO_2), 0.01-5% by mass of Ag and 0.01-2% by mass of Zr (as ZrO_2), and (c) inevitable impurities.

29. (currently amended): ~~The~~A high-strength, low-temperature-sintered ceramic composition ~~according to claim 18~~having a structure comprising $\text{SrAl}_2\text{Si}_2\text{O}_8$ and Al_2O_3 , said ceramic composition having a bending strength of 300 MPa or more, wherein it comprises (a) 100% by mass of main components comprising 10-60% by mass of Al (as Al_2O_3), 25-60% by mass of Si (as SiO_2), 7.5-50% by mass of Sr (as SrO) and 20% or less by mass of Ti (as TiO_2), (b) auxiliary components comprising at least one selected from the group consisting of 0.1-10% by mass of Bi (as Bi_2O_3), 0.1-5% by mass of Na (as Na_2O), 0.1-5% by mass of K (as K_2O) and 0.1-5% by mass of Co (as CoO), and at least one selected from the group consisting of 0.01-5% by mass of Cu (as CuO), 0.01-5% by mass of Mn (as MnO_2), 0.01-5% by mass of Ag and 0.01-2% by mass of Zr (as ZrO_2), and (c) inevitable impurities.

30. (currently amended): A method for producing the high-strength, low-temperature-sintered ceramic composition recited in ~~claim 18~~any one of claims 18-20 or 22-29, by sintering~~comprising calcining a ceramic green body comprising~~ aluminum oxide, silicon oxide and strontium oxide, or aluminum oxide, silicon oxide, strontium oxide and titanium oxide ~~as main starting materials to obtain a calcined powder comprising a silicate glass containing Al_2O_3 and TiO_2 , molding said calcined powder to a ceramic green body, followed by sintering said green body under such temperature and time conditions that a ratio of hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ in a $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal formed in a ceramic structure becomes 5% or more.~~

31. (previously presented): A laminated electronic part comprising pluralities of dielectric layers made of the high-strength, low-temperature-sintered ceramic composition

recited in claim 18, each of said dielectric layers being provided with a conductive pattern of a low-melting-point metal.

32. (previously presented): The laminated electronic part according to claim 31, wherein said low-melting-point metal is silver, copper, gold or an alloy thereof.

33. (previously presented): The laminated electronic part according to claim 31, wherein said conductive pattern constitutes an inductance element and/or a capacitance element.

34. (previously presented): The laminated electronic part according to claim 31, onto which at least one selected from the group consisting of an inductance element, a capacitance element, a switching element and a filter element is mounted.

35. (new): The high-strength, low-temperature-sintered ceramic composition according to claim 18, further comprising monoclinic $\text{SrAl}_2\text{Si}_2\text{O}_8$.

36. (new): A method for producing the high-strength, low-temperature-sintered ceramic composition recited in claim 35, comprising calcining aluminum oxide, silicon oxide and strontium oxide, or aluminum oxide, silicon oxide, strontium oxide and titanium oxide to obtain a calcined powder comprising a silicate glass containing Al_2O_3 and TiO_2 , molding said calcined powder to a ceramic green body, followed by sintering said green body under such temperature and time conditions that a ratio of hexagonal $\text{SrAl}_2\text{Si}_2\text{O}_8$ in a $\text{SrAl}_2\text{Si}_2\text{O}_8$ crystal formed in a ceramic structure becomes 5% or more.